

SEMICONDUCTOR

200 mW LL-34 Hermetically Sealed Glass Fast Switching Schottky Barrier Diode

Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
PD	Power Dissipation	200	mW	
T _{STG}	Storage Temperature Range	-65 to +125	°C	
TJ	Operating Junction Temperature	+125	°C	
V _{RRM}	Repetitive Peak Reverse Voltage	30	V	
V _R	Maximum DC Blocking Voltage	30	V	
I _{F(AV)}	Average Forward Rectified Current	200	mA	
I _{FSM}	Peak Forward Surge Current	4	А	

These ratings are limiting values above which the serviceability of the diode may be impaired.

Specification Features:

- Low Forward Voltage Drop
- LL-34 Package (JEDEC)
- Through-Hole Device Type Mounting
- Hermetically Sealed Glass
- Compression Bonded Construction
- All External Surfaces Are Corrosion Resistant And Leads Are Readily Solderable
- RoHS Compliant
- Solder Hot Dip Tin (Sn) Lead Finish

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Limits			11
		Test Condition	Min	Тур	Max	Unit
Bv	Breakdown Voltage	I _R =10μΑ	30			Volts
I _R	Reverse Leakage Current	V _R =25V			2	uA
V _F	Forward Voltage	I _F =0.1mA			0.24	
		I _F =1mA			0.32	
		I _F =10mA			0.40	Volts
		I _F =30mA			0.50	
		I _F =100mA			0.80	
T _{RR}	Reverse Recovery Time	I _F =I _R =10mA				
		$R_L=100\Omega$		5		nS
		I _{RR} =1mA				
С	Capacitance	$V_R=1V$, f=1 M_{HZ}		7	10	pF



DEVICE MARKING DIAGRAM

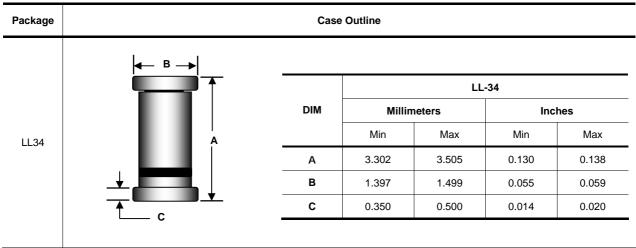
Cathode Anode

Cathode Band Color: Black

ELECTRICAL SYMBOL



Package Outline



Notes:

1. All dimensions are within DO213AC JEDEC standard.

2. LL-34 polarity denoted by cathode band.

